

SIMULATION RESULTS OF DIFFERENTIAL AMPLIFIER WITH ACTIVE LOAD

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PROJECT TITLE : Design and Simulation of differential
Amplifier with active load using cmos
180nm technology in LTSpice

DESIGN SPECIFICATIONS :

$V_d = 1.8\text{v}$

$\text{Gain} > 40\text{db}$

$C_l = 10\text{pf}$

$\text{ICMR}(\text{max}) = 1.6\text{v}$

$\text{ICMR}(\text{min}) = 0.8\text{v}$

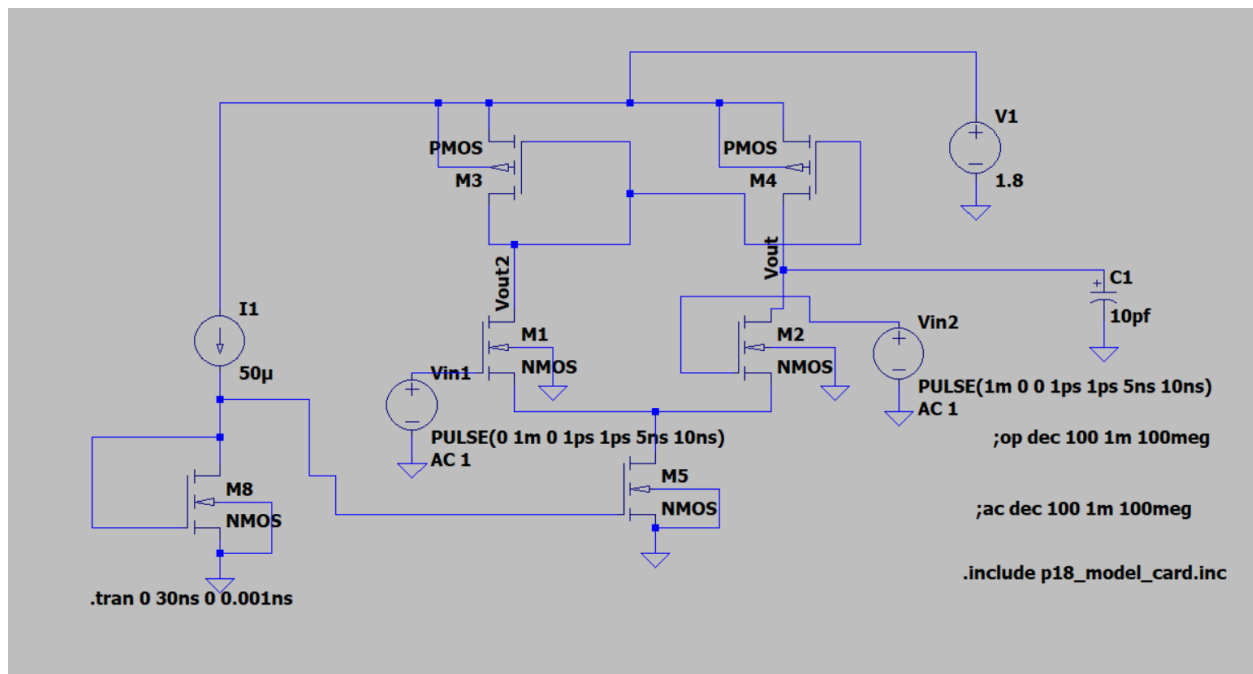
$\text{Slew-Rate} = 5\text{V}/\mu\text{s}$

$\text{Gain Band Width Product} = 5\text{Mhz}$

CALCULATIONS :

With the above specifications I have calculated all the design parameters. I later simulated the circuit in LTSpice And calculated all the parameters like gain-band-product, Differential AC gain, Slewrate, Common mode gain.

CIRCUIT DIAGRAM :



DIFFERENTIAL AMPLIFIER WITH ACTIVE LOAD

(180 nm TECHNOLOGY)

DESIGN SPECIFICATIONS :

$$V_{DD} = 1.8V$$

$$A_V \geq 40dB$$

$$C_L = 10pF$$

$$ICMR (MAX) = 1.6V$$

$$ICMR (MIN) = 0.8V$$

$$SLEW-RATE = 5V/\mu sec$$

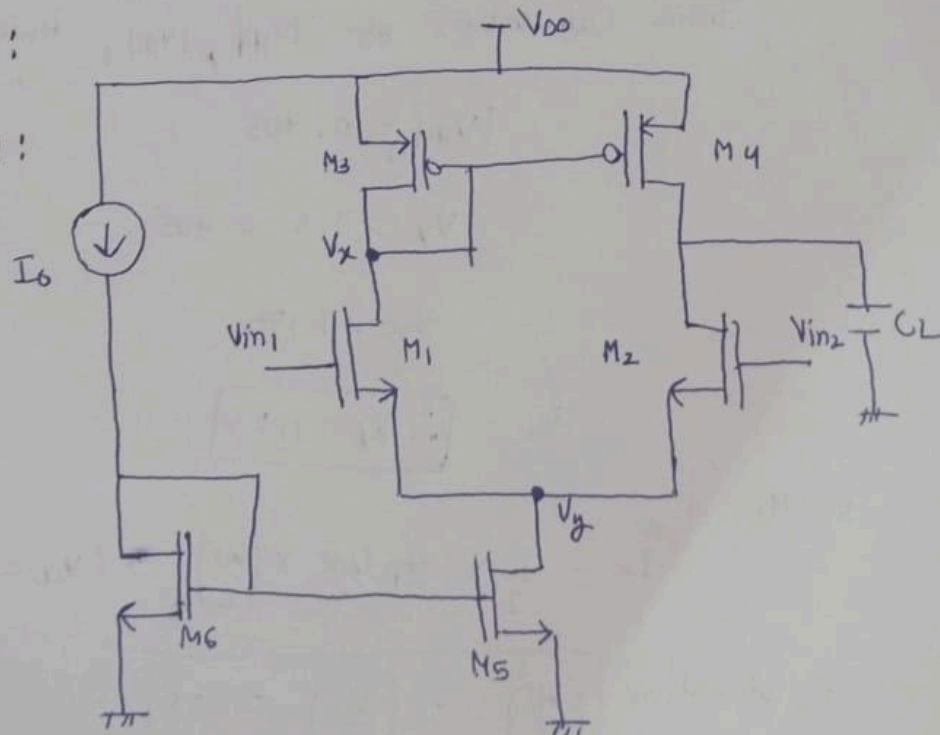
$$GAIN-BANDWIDTH PRODUCT = 5 megHz$$

$M_1, M_2 \rightarrow$ Matched

$M_3, M_4 \rightarrow$ Matched

CALCULATIONS :

CIRCUIT DIAGRAM :



① Calculation of I_0

$$\text{slew rate} = \frac{dV_o}{dt} = \frac{I_0}{C_L}$$

$$I_0 = C_L \times \text{slew-rate}$$

$$I_0 = 10\text{pf} \times 5\text{V}/\mu\text{s}$$

$$\boxed{I_0 = 50\mu\text{A}}$$

② Calculation of $\left(\frac{W}{L}\right)_3$ and $\left(\frac{W}{L}\right)_4$

$$\text{ICMR}(\text{Max}) = 1.6\text{V}$$

$$V_{DS3} > V_{GS3} - |V_{TP}|_3$$

$$V_D > V_G - |V_{TP}|_3$$

$$V_X > (V_{in})_{\text{max}} - |V_{TP}|_3$$

From Calculation of $|V_{TP}|$, $|V_{TN}|$, $\mu_n C_{ox}$, $\mu_p C_{ox}$

$$|V_{TP}|_n = 0.405$$

$$V_X > 1.6 - 0.405$$

$$V_X > 1.195$$

$$\boxed{\therefore V_X = 1.2\text{V}}$$

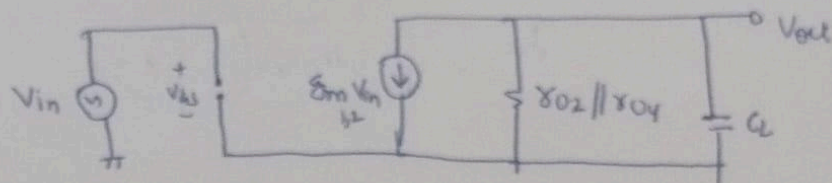
For M_3 ,

$$\frac{I_0}{2} = \frac{1}{2} \times \mu_p C_{ox} \times \left(\frac{W}{L}\right)_3 \times (V_{DD} - V_X - |V_{TP}|)^2$$

By Calculation
we get

$$\boxed{\left(\frac{W}{L}\right)_3 = \left(\frac{W}{L}\right)_4 = 28}$$

③ Calculation of M_1, M_2 from Gain-Bandwidth product :- parameters



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$$\frac{V_{out}}{V_{in}} = \frac{-g_{m1,2} (r_{o2} || r_{o4})}{1 + sC_L (r_{o2} || r_{o4})}$$

$$\infty \text{ gain} = g_{m1,2} (r_{o2} || r_{o4})$$

$$3\text{-dB cutoff Frequency} = \frac{1}{2\pi \times (r_{o2} || r_{o4}) \times C_L}$$

$$GBP = g_{m1,2} (r_{o2} || r_{o4}) \frac{1}{2\pi \times (r_{o2} || r_{o4}) \times C_L}$$

$$GBP = \frac{g_{m1,2}}{2\pi \times C_L}$$

$$\text{Given } GBP = 5 \text{ MHz}$$

$$5 \times 10^6 = \frac{g_{m1,2}}{2 \times 3.1416 \times 10 \times 10^{-12}}$$

$$g_{m1,2} = 314.16 \mu$$

$$I_D = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right)_{1,2} (V_{GS} - V_T)^2$$

$$g_m = \sqrt{2 \mu_n C_{ox} \left(\frac{W}{L}\right)_{1,2} \times I_D}$$

$$\left(\frac{W}{L}\right)_{1,2} = \frac{g_{m1,2}^2}{2 I_D \mu_n C_{ox}}$$

$$\left(\frac{W}{L}\right)_{1,2} \approx 9.2952$$

Taking $\boxed{\left(\frac{W}{L}\right)_{1,2} \approx 10}$

④ Calculating the value of $\left(\frac{W}{L}\right)_5$ for M_5 :-

$$I_{CMR}(\min) = 0.8V$$

$$V_{GS1} < V_{\min}(I_{CMR}) - V_{th}$$

$$V_y < V_{\min}(I_{CMR}) - V_{GS1}$$

$$\frac{1}{2} \mu_n (V_{GS1} - V_{th})^2 C_{ox} = \frac{I_{D0}}{2}$$

$$V_y = V_{GS5} - V_T$$

$$\boxed{V_{GS1} = 0.15135V}$$

$$\boxed{V_y < 0.2865}$$

$$I_{D5} = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right)_5 (V_y)^2$$

$$I_{D5} = 50\mu A$$

$$\boxed{\therefore \left(\frac{W}{L}\right)_5 \approx 6}$$

⑤ Calculating $\left(\frac{W}{L}\right)_6$

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By Current Mirroring

$$\frac{I_1}{I_0} = \frac{\left(\frac{W}{L}\right)_5}{\left(\frac{W}{L}\right)_6} = 1$$

$$\boxed{\left(\frac{W}{L}\right)_5 = \left(\frac{W}{L}\right)_6 = 56}$$

DESIGN PARAMETERS:-

$$\left(\frac{W}{L}\right)_1 = \left(\frac{W}{L}\right)_2 = 10$$

$$W_1 = W_2 = 10 \mu\text{m}$$

$$L_1 = L_2 = 1 \mu\text{m}$$

$$\left(\frac{W}{L}\right)_3 = \left(\frac{W}{L}\right)_4 = 28$$

$$W_1 = W_2 = 28 \mu\text{m}$$

$$L_1 = L_2 = 1 \mu\text{m}$$

$$\left(\frac{W}{L}\right)_5 = \left(\frac{W}{L}\right)_6 = 6$$

$$W_5 = W_6 = 6 \mu\text{m}$$

$$L_6 = L_5 = 1 \mu\text{m}$$

RESULT OBTAINED :

① DC operating point - given in fig for $(V_{in})_{cm} = 0.8V$
 $= I_{CMRmin}$

② DC operating point - given in fig for $(V_{in})_{cm} = 1.6V$
 $= I_{CMRmax}$

③ Differential - AC gain = 44.5 dB

$$V_{in1} = 1V(AC) + AC(1) \rightarrow \text{Ophone}$$

$$V_{in2} = 1V(AC) + AC(1) \rightarrow \text{Bopphone}$$

④ Common Mode gain = 0.0096605

⑤ Unity - Gain Bandwidth product = 10.1 MHz

⑥ Slew - Rate obtained = 5.9 V/ μ s

SIMULATION RESULTS :

The following figures shows the results of the simulations obtained in LTSpice.

1) DC Operating Point : following image shows the dc operating point when $V_{in}(cm)=0.8v$ (DC)

```

Semiconductor Device Operating Points:
      --- BSIM3 MOSFETS ---
Name:      m1
Model:     rmos
Id:        2.27e-05
Igs:       6.06e-01
Ihs:       1.03e+00
Ibs:       -1.94e-01
Ahh:       4.66e-01
Ahsat:     1.21e-01
Im:        3.08e-04
Ids:       5.59e-07
Imb:       8.03e-05
Ibd:       0.00e+00
Ibs:       0.00e+00
Igssov:    7.02e-15
Igdsov:    6.97e-15
Igbsov:    9.78e-19
IQgdVgb:   8.07e-14
IQgdVsb:   -6.97e-15
IQgdVdb:   -6.94e-14
IQddVgb:   -3.39e-14
IQddVsb:   6.97e-15
IQddVdb:   3.47e-14
IQbdVgb:   -1.29e-14
IQbdVsb:   -2.51e-18
IQbdVdb:   -6.89e-15

Name:      m2
Model:     rmos
Id:        2.27e-05
Igs:       6.06e-01
Ihs:       1.03e+00
Ibs:       -1.94e-01
Ahh:       4.66e-01
Ahsat:     1.21e-01
Im:        3.08e-04
Ids:       5.59e-07
Imb:       8.03e-05
Ibd:       0.00e+00
Ibs:       0.00e+00
Igssov:    7.02e-15
Igdsov:    6.97e-15
Igbsov:    9.78e-19
IQgdVgb:   8.07e-14
IQgdVsb:   -6.97e-15
IQgdVdb:   -6.94e-14
IQddVgb:   -3.39e-14
IQddVsb:   6.97e-15
IQddVdb:   3.47e-14
IQbdVgb:   -1.29e-14
IQbdVsb:   -2.51e-18
IQbdVdb:   -6.89e-15

Name:      m5
Model:     rmos
Id:        4.53e-05
Igs:       6.84e-01
Ihs:       1.94e-01
Ibs:       0.00e+00
Ahh:       4.07e-01
Ahsat:     2.10e-01
Im:        2.95e-04
Ids:       6.37e-05
Imb:       1.73e-04
Ibd:       0.00e+00
Ibs:       0.00e+00
Igssov:    4.21e-15
Igdsov:    4.18e-15
Igbsov:    9.78e-19
IQgdVgb:   5.09e-14
IQgdVsb:   -6.40e-15
IQgdVdb:   -5.22e-14
IQddVgb:   -2.21e-14
IQddVsb:   6.35e-15
IQddVdb:   2.70e-14
IQbdVgb:   -6.62e-15
IQbdVsb:   -2.12e-15
IQbdVdb:   -6.12e-15

Name:      m8
Model:     rmos
Id:        5.00e-05
Igs:       6.84e-01
Ihs:       6.84e-01
Ibs:       0.00e+00
Ahh:       4.04e-01
Ahsat:     2.12e-01
Im:        3.58e-04
Ids:       2.93e-06
Imb:       4.89e-04
Ibd:       0.00e+00
Ibs:       0.00e+00
Igssov:    4.21e-15
Igdsov:    4.18e-15
Igbsov:    9.78e-19
IQgdVgb:   4.93e-14
IQgdVsb:   -4.05e-15
IQgdVdb:   -7.51e-14
IQddVgb:   -2.06e-14
IQddVsb:   4.11e-15
IQddVdb:   4.00e-14
IQbdVgb:   -8.03e-15
IQbdVsb:   2.04e-18
IQbdVdb:   -9.17e-15

Name:      m3
Model:     pmos
Id:        -2.27e-05
Igs:       -5.81e-01
Ihs:       -5.81e-01
Ibs:       0.00e+00
Ahh:       -4.20e-01
Ahsat:     -1.42e-01
Im:        2.54e-04
Ids:       3.05e-06
Imb:       8.03e-05
Ibd:       0.00e+00
Ibs:       0.00e+00
Igssov:    1.92e-14
Igdsov:    1.93e-14
Igbsov:    9.60e-19
IQgdVgb:   2.23e-13
IQgdVsb:   -1.89e-14
IQgdVdb:   -1.96e-13
IQddVgb:   -9.38e-14
IQddVsb:   1.91e-14
IQddVdb:   9.89e-14
IQbdVgb:   -3.53e-14
IQbdVsb:   -5.41e-18
IQbdVdb:   -2.14e-14

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2)DC Operating Point when Vin(cm)=1.6v (DC)

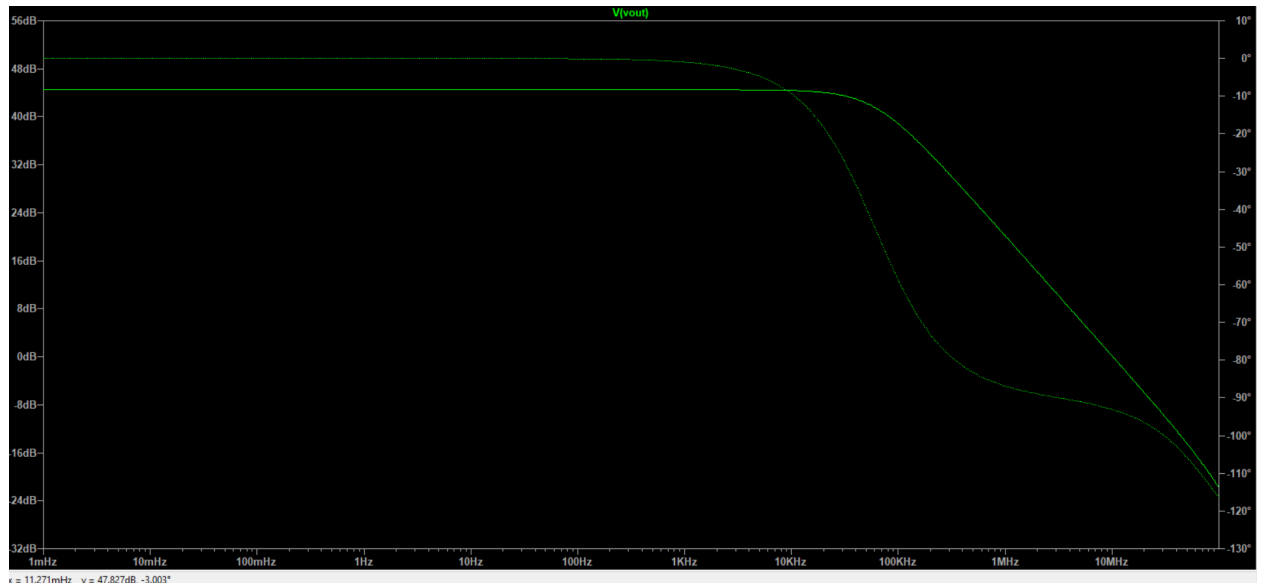
```

--- BSIM3 MOSFETS ---
Name:      m1      m2      m5      m8      m3
Model:     nmos    nmos    nmos    nmos    pmos
Id:        2.52e-05  2.52e-05  5.04e-05  5.00e-05  -2.52e-05
Vgs:       7.66e-01  7.66e-01  6.84e-01  6.84e-01  -5.90e-01
Vds:       3.76e-01  3.76e-01  8.34e-01  6.84e-01  -5.90e-01
Vbs:       -8.34e-01 -8.34e-01  0.00e+00  0.00e+00  0.00e+00
Vth:       6.29e-01  6.29e-01  4.03e-01  4.04e-01  -4.20e-01
Vdsat:     1.33e-01  1.33e-01  2.12e-01  2.12e-01  -1.49e-01
Gm:        3.34e-04  3.34e-04  3.60e-04  3.58e-04  2.70e-04
Gds:       1.33e-06  1.33e-06  2.74e-06  2.93e-06  3.31e-06
Gmb        7.18e-05  7.18e-05  5.78e-04  4.89e-04  8.53e-05
Cbd:       0.00e+00  0.00e+00  0.00e+00  0.00e+00  0.00e+00
Cbs:       0.00e+00  0.00e+00  0.00e+00  0.00e+00  0.00e+00
Cgsov:     7.02e-15  7.02e-15  4.21e-15  4.21e-15  1.92e-14
Cgdov:     6.97e-15  6.97e-15  4.18e-15  4.18e-15  1.93e-14
Cgbov:     9.78e-19  9.78e-19  9.78e-19  9.78e-19  9.60e-19
dQgdVgb:   7.94e-14  7.94e-14  4.93e-14  4.93e-14  2.23e-13
dQgdVdb:   -7.07e-15  -7.07e-15  -4.04e-15  -4.05e-15  -1.89e-14
dQgdVsb:   -6.87e-14  -6.87e-14  -8.21e-14  -7.51e-14  -1.96e-13
dQddVgb:   -3.41e-14  -3.41e-14  -2.06e-14  -2.06e-14  -9.40e-14
dQddVdb:   7.05e-15  7.05e-15  4.10e-15  4.11e-15  1.91e-14
dQddVsb:   3.32e-14  3.32e-14  4.40e-14  4.00e-14  9.92e-14
dQbdVgb:   -1.12e-14  -1.12e-14  -8.04e-15  -8.03e-15  -3.52e-14
dQbdVdb:   -6.74e-17  -6.74e-17  1.12e-17  2.04e-18  -7.15e-18
dQbdVsb:   -4.69e-15  -4.69e-15  -1.01e-14  -9.17e-15  -2.15e-14

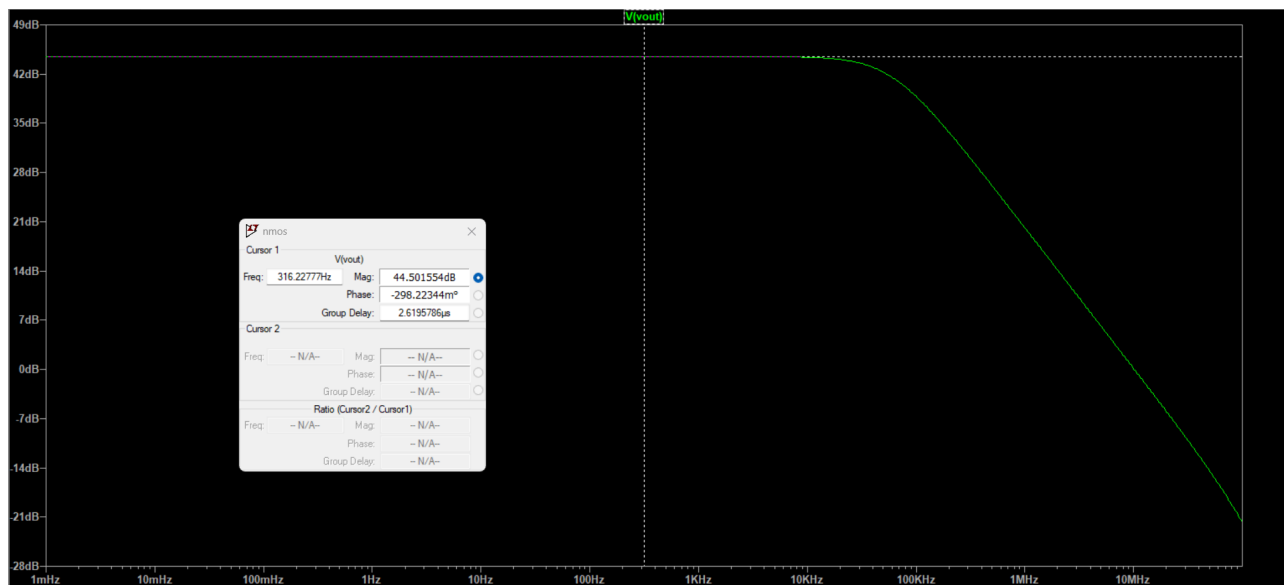
Name:      m4
Model:     pmos
Id:        -2.52e-05
Vgs:       -5.90e-01
Vds:       -5.90e-01
Vbs:       0.00e+00
Vth:       -4.20e-01
Vdsat:     -1.49e-01
Gm:        2.70e-04
Gds:       3.31e-06
Gmb        8.53e-05
Cbd:       0.00e+00
Cbs:       0.00e+00
Cgsov:     1.92e-14
Cgdov:     1.93e-14
Cgbov:     9.60e-19
dQgdVgb:   2.23e-13
dQgdVdb:   -1.89e-14
dQgdVsb:   -1.96e-13
dQddVgb:   -9.40e-14
dQddVdb:   1.91e-14
dQddVsb:   9.92e-14

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3) AC gain plot Gain Obtained=44.5 db

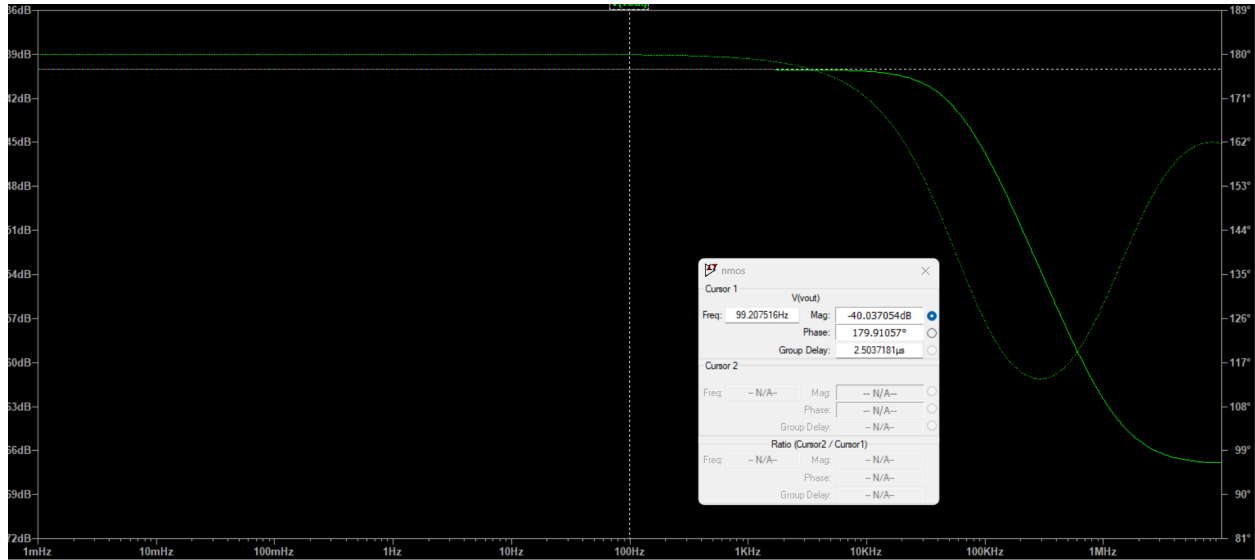


4) AC Gain Calculation :

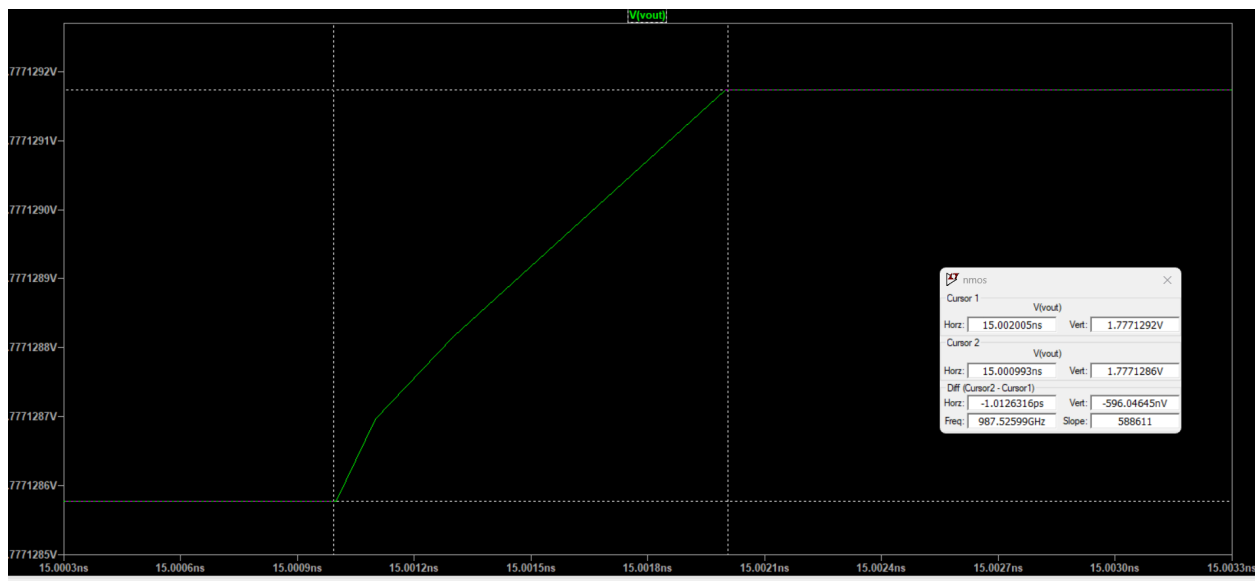


5) Common Mode Gain Plot :

Value obtained = 0.009



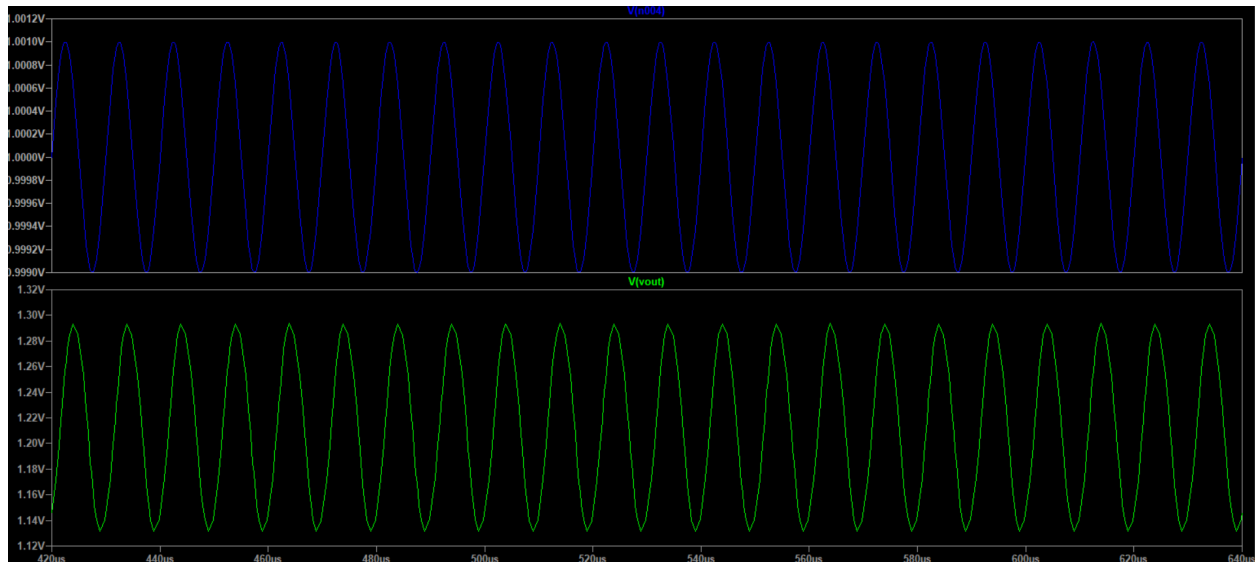
6) Slew Rate Obtained = 5.9 V/us



8) Unity Gain Bandwidth Frequency : 10.1Mhz



9) Transient Analysis Result : (with differential Voltage)



OBTAINED RESULT SPECIFICATIONS :

RESULT OBTAINED :

- ① DC operating point - given in fig for $(V_{in})_{cm} = 0.8V$
 $= I_{CMRmin}$
- ② DC operating point - given in fig for $(V_{in})_{cm} = 1.6V$
 $= I_{CMRmax}$

③ Differential - AC gain = 44.5 dB

$$V_{in1} = 1V(AC) + AC(1) \rightarrow \text{ophone}$$

$$V_{in2} = 1V(AC) + AC(1) \rightarrow \text{phone}$$

④ Common Mode gain = 0.0096605

⑤ Unity - Gain Bandwidth product = 10.1 MHz

⑥ Slew - Rate obtained = 5.9 V/ μ s